

7 W Ka Band Packaged Power Amplifier



Product Description

The TriQuint TGA4915-CP is a compact 7 Watt High Power Amplifier for Ka band applications. The part is designed using TriQuint's proven standard 0.25 um gate Power pHEMT production process.

The TGA4915-CP provides a nominal 38 dBm of output power at an input power level of 21 dBm with a small signal gain of 22 dB.

The part is ideally suited for low cost emerging markets such as base station transmitters for satellite ground terminals and point to point radio.

Key Features and Performance

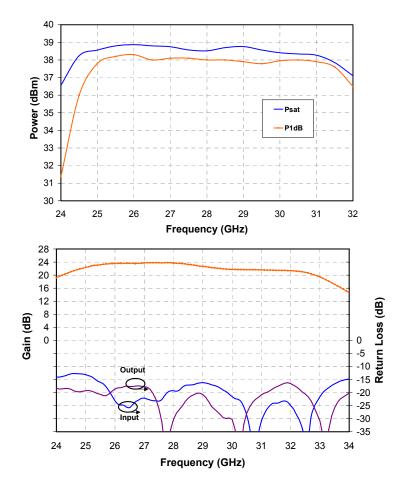
- Frequency Range: 26 31 GHz
- 38 dBm Typical Psat @ Pin =21 dBm
- 22 dB Nominal Gain
- 15 dB Typical Return Loss
- 0.25µm pHEMT Technology
- Bias Conditions: Vd = 6V, Idq = 4.2 A
- Package Dimensions: 0.526 x 0.650 x 0.073 in

Primary Applications

- Satellite Ground Terminals
- Point to Point

Preliminary Measured Performance

Bias Conditions: Vd=6 V Idq=4.2 A



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Datasheet subject to change without notice.



TABLE I MAXIMUM RATINGS 1/

Symbol	Parameter	Value	Notes
V*	Positive Supply Voltage	8 V	
V	Negative Supply Voltage Range	-3V TO 0V	
۱*	Positive Supply Current (Quiescent)	8 A	
_G	Gate Supply Current	124 mA	
P _{IN}	Input Continuous Wave Power	27 dBm	
P _D	Power Dissipation	50 W	
Т _{СН}	Operating Channel Temperature	200 °C	<u>2/</u>
Тм	Mounting Temperature (30 Seconds)	210 °C	
T _{STG}	Storage Temperature	-65 to 150 °C	

- <u>1</u>/ These ratings represent the maximum operable values for this device. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device and/or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.
- 2/ Junction operating temperature will directly affect the device median lifetime. For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.



TABLE II RF CHARACTERIZATION TABLE $(T_A = 25 \text{ °C}, \text{ Nominal})$ (Vd = 6 V, Id = 4.2 A)

SYMBOL	PARAMETER	TEST CONDITION	TYPICAL	UNITS
Gain	Small Signal Gain	F = 26-31 GHz	22	dB
IRL	Input Return Loss	F = 26-31 GHz	15	dB
ORL	Output Return Loss	F = 26-31 GHz	15	dB
PWR	Output Power @ P1dB	F = 26-31 GHz	38	dBm

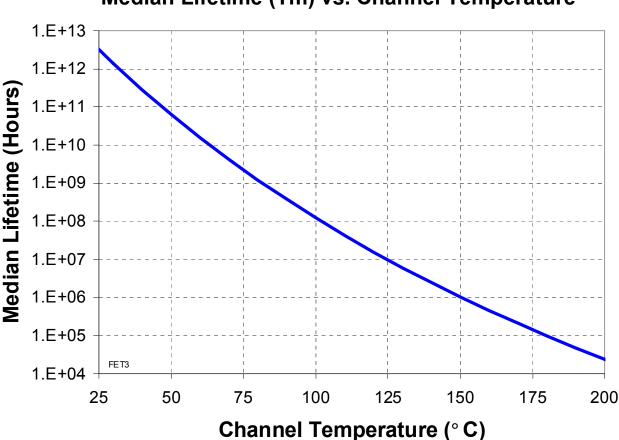
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TABLE III THERMAL INFORMATION

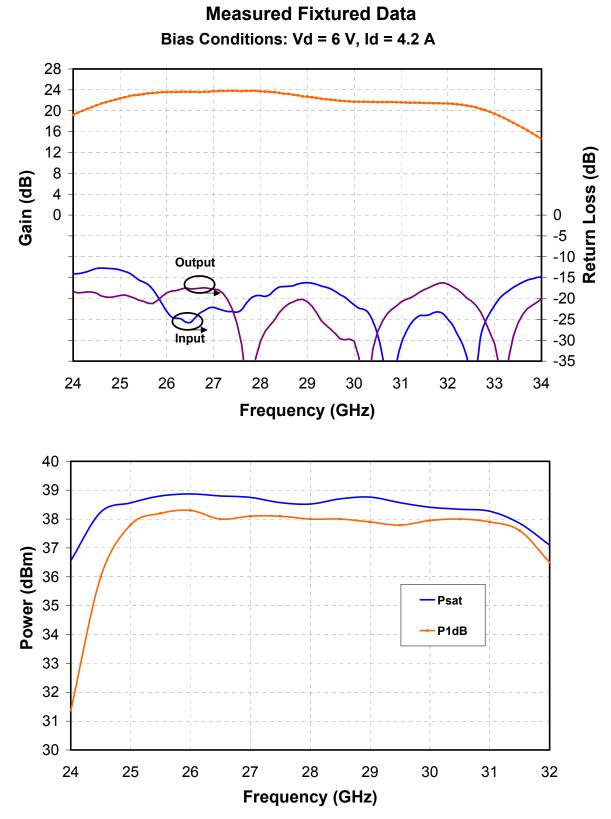
Parameter	Test Conditions	Т _{сн} (°С)	θ _{JC} (°C/W)	T _m (hours)
θ _{Jc} Thermal Resistance (Channel to Backside of Package)	$V_{D} = 6 V$ $I_{D} = 4.2 A$ $P_{DISS} = 25.2 W$	128	2.3	7.4 E+6
θ _{Jc} Thermal Resistance (Channel to Backside of Package)	Vd = 8 V Id = 7.1 A @ Psat P _{diss} = 50 W P _{out} = 7 W (RF)	200	2.3	2.3 E+4

 Note: Carrier at 85 °C baseplate temperature. Worst case is at saturated output power when DC power consumption rises to 57 W with 7 W RF power delivered to the load. Power dissipated is 50 W and the temperature rise in the channel is 115 °C.

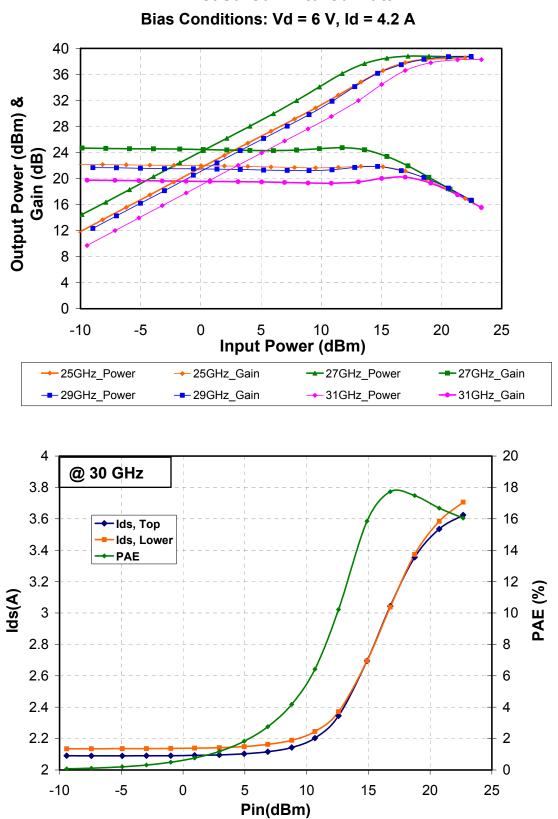


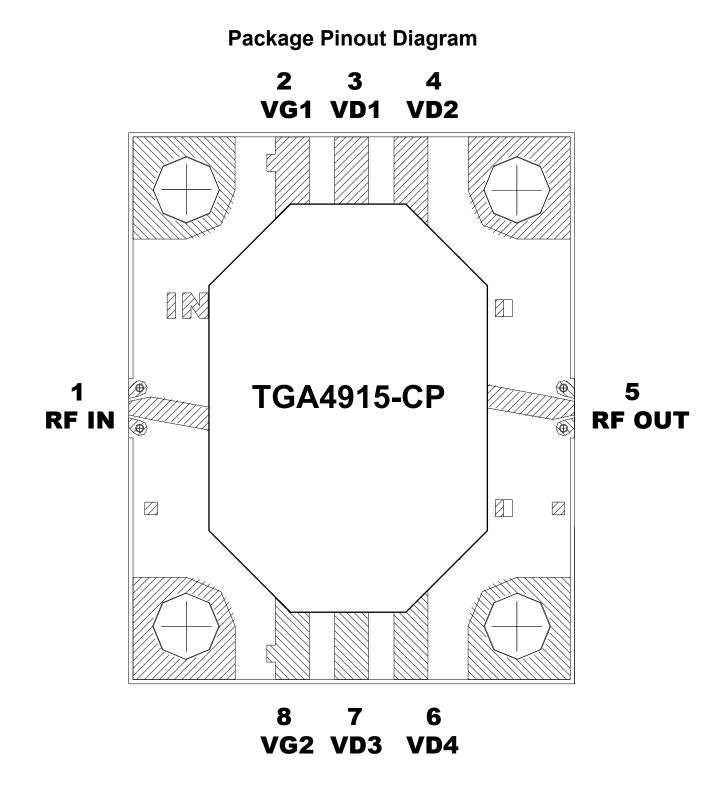
Median Lifetime (Tm) vs. Channel Temperature









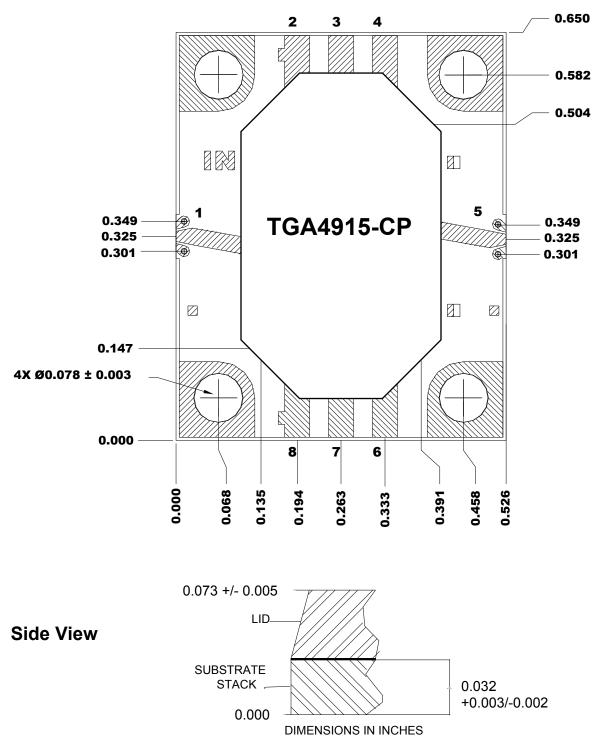


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Assembly of a TGA4915-CP into a Module

Manual Assembly for Prototypes

1. Clean the module with Acetone. Rinse with alcohol and DI water. Allow the module to fully dry.

2. To improve the thermal and RF performance, we recommend attaching a heatsink to the bottom of the package. If the TGA4915-CP is mounted to the heatsink with mounting screws, we recommend an indium shim or other compliant material be inserted between the TGA4915-CP and the heatsink to reduce thermal contact resistance due to air gaps. The TGA4915-CP may also be attached to the heatsink using SN63 solder or any other Tin/Lead solder. The TGA4915-CP may also be mounted with DieMat DM6030HK conductive epoxy or similar thermally and electrically conductive epoxy.

3. The DC and RF interconnects may be gold bondwires or gold ribbons. The RF interconnects should be as short as possible. A minimum of two 1 mil wires are recommended for the RF Input, RF Output, Vg, and Vd1 and Vd3. Six bondwires are recommended for Vd2 and Vd4.

ORDERING INFORMATION

PART	PACKAGE STYLE
TGA4915-CP	CARRIER PLATE